TEXAS INSTRUMENTS

TMUX1237 3-Ω Low R$_{ON}$, 5-V, 2:1 (SPDT) General Purpose Switch With No Overshoot When Switching Inputs

1 Features

- No Overshoot When Switching Inputs
- Rail-to-rail Operation
- Bidirectional Signal Path
- 1.8 V Logic Compatible
- Fail-safe Logic
- Low On-resistance: 3 Ω
- Wide Supply Range: 1.08 V to 5.5 V
- -40°C to +125°C Operating Temperature
- Low Supply Current: 7 nA
- Break-before-make Switching
- ESD Protection HBM: 2000 V

2 Applications

- Analog and Digital Switching
- I^{2}C and SPI Bus Multiplexing
- Remote Radio Units (RRU)
- Active Antenna System mMIMO (AAS)
- Rack Server
- Network Interface Card (NIC)
- Barcode Scanner
- Building Automation
- Analog Input Module
- Motor Drives
- Video Surveillance
- Electronic Point of Sale
- Desktop PC
- Appliances

3 Description

The TMUX1237 is a general purpose 2:1, single-pole double-throw (SPDT), switch that supports a wide operating range of 1.08 V to 5.5 V. The device supports bidirectional analog and digital signals on the source (Sx) and drain (D) pins ranging from GND to V$_{DD}$. The state of the select pin (SEL) controls which of the two sources pins are connected to the drain pin. Additionally, the TMUX1237 has a low supply current of 7 nA which enables the device to be used in a host of handheld or low power applications.

The TMUX1237 improves system reliability by eliminating overshoot that might occur in a system due to switching between two voltage levels on the source (Sx) pins. In addition, the TMUX1237 also maintains fast switching times, enabling it to improve system performance for a wide range of applications from communications equipment to building automation.

All logic inputs have 1.8 V logic compatible thresholds, ensuring both TTL and CMOS logic compatibility when operating in the valid supply voltage range. Fail-Safe Logic circuitry allows voltages on the control pins to be applied before the supply pin, protecting the device from potential damage.

Device Information[1]

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TMUX1237	SC70 (6)	2.00 mm × 1.25 mm

(1) For all available packages, see the package option addendum at the end of the data sheet.

TMUX1237 Block Diagram
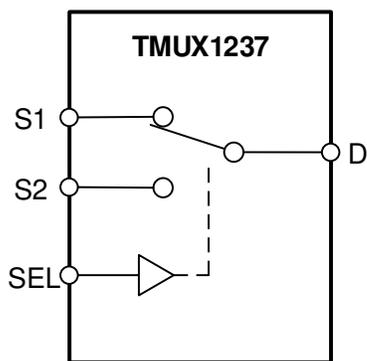

Application Example

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (Decemeber 2019) to Revision A   **Page**

- Changed the document status From: *Product Preview* To: *Production Data* 1

5 Pin Configuration and Functions

DCK Package
6-Pin SC70
Top View

```
        ┌──────────────────┐
        │        ○         │
S2  ───┤  1            6   ├─── SEL
        │                  │
VDD ───┤  2            5   ├─── GND
        │                  │
S1  ───┤  3            4   ├─── D
        │                  │
        └──────────────────┘
         Not to scale
```
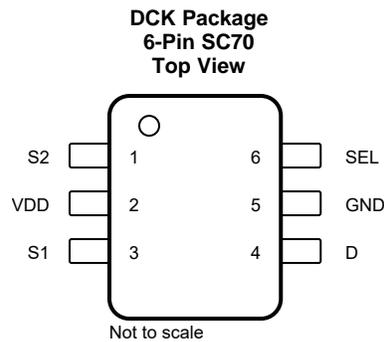
Pin Functions

PIN		TYPE[1]	DESCRIPTION[2]
NAME	NO.		
S2	1	I/O	Source pin 2. Can be an input or output.
V$_{DD}$	2	P	Positive power supply. This pin is the most positive power-supply potential. For reliable operation, connect a decoupling capacitor ranging from 0.1 µF to 10 µF between V$_{DD}$ and GND.
S1	3	I/O	Source pin 1. Can be an input or output.
D	4	I/O	Drain pin. Can be an input or output.
GND	5	P	Ground (0 V) reference
SEL	6	I	Select pin: controls state of the switch according to Table 1. (Logic Low = S1 to D, Logic High = S2 to D)

(1) I = input, O = output, I/O = input and output, P = power.
(2) Refer to Device Functional Modes for what to do with unused pins.

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted).[1][2][3]

		MIN	MAX	UNIT
V_{DD}	Supply voltage	−0.5	6	V
V_{SEL} or V_{EN}	Logic control input pin voltage (SEL)	−0.5	6	V
I_{SEL} or I_{EN}	Logic control input pin current (SEL)	−30	30	mA
V_S or V_D	Source or drain voltage (Sx, D)	−0.5	V_{DD}+0.5	V
I_S or $I_{D\ (CONT)}$	Source or drain continuous current (Sx, D)	−50	50	mA
I_K	Diode clamp current[4]	−30	30	mA
T_{stg}	Storage temperature	−65	150	°C
T_J	Junction temperature		150	°C

(1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
(3) All voltages are with respect to ground, unless otherwise specified.
(4) Pins are diode-clamped to the power-supply rails. Over voltage signals must be voltage and current limited to maximum ratings.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins[1]	±2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins[2]	±750	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted).

		MIN	NOM	MAX	UNIT
V_{DD}	Supply voltage	1.08		5.5	V
V_S or V_D	Signal path input/output voltage (source or drain pin) (Sx, D)	0		V_{DD}	V
V_{SEL}	Logic control input pin voltage (SEL)	0		5.5	V
I_S or I_D	Signal path continuous current (source or drain pins: Sx, D)	−50		50	mA
T_A	Ambient temperature	−40		125	°C

6.4 Thermal Information

	THERMAL METRIC[1]	TMUX1237	UNIT
		SC70 (DCK)	
		6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	243.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	180.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	106.3	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	89.1	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	106.0	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics (V$_{DD}$ = 5 V ±10 %), GND = 0 V unless otherwise specified.

At T$_A$ = 25°C, V$_{DD}$ = 5 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
ANALOG SWITCH							
R$_{ON}$	On-resistance	V$_S$ = 0 V to V$_{DD}$ I$_{SD}$ = 10 mA Refer to On-Resistance	25°C		3		Ω
			−40°C to +85°C			5	Ω
			−40°C to +125°C			5	Ω
ΔR$_{ON}$	On-resistance matching between channels	V$_S$ = 0 V to V$_{DD}$ I$_{SD}$ = 10 mA Refer to On-Resistance	25°C		0.15		Ω
			−40°C to +85°C			1	Ω
			−40°C to +125°C			1	Ω
R$_{ON}$ FLAT	On-resistance flatness	V$_S$ = 0 V to V$_{DD}$ I$_{SD}$ = 10 mA Refer to On-Resistance	25°C		1.5		Ω
			−40°C to +85°C		2		Ω
			−40°C to +125°C		3		Ω
I$_{S(OFF)}$	Source off leakage current[1]	V$_{DD}$ = 5 V Switch Off V$_D$ = 4.5 V / 1.5 V V$_S$ = 1.5 V / 4.5 V Refer to Off-Leakage Current	25°C		±75		nA
			−40°C to +85°C	−150		150	nA
			−40°C to +125°C	−175		175	nA
I$_{D(ON)}$ I$_{S(ON)}$	Channel on leakage current	V$_{DD}$ = 5 V Switch On V$_D$ = V$_S$ = 4.5 V / 1 V Refer to On-Leakage Current	25°C		±200		nA
			−40°C to +85°C	−500		500	nA
			−40°C to +125°C	−750		750	nA
LOGIC INPUTS							
V$_{IH}$	Input logic high		-40°C to 125°C	1.32		5.5	V
V$_{IL}$	Input logic low		-40°C to 125°C	0		0.87	V
I$_{IH}$ I$_{IL}$	Input leakage current		25°C		±0.005		µA
I$_{IH}$ I$_{IL}$	Input leakage current		−40°C to +125°C			±0.05	µA
C$_{IN}$	Digital input capacitance		25°C		1		pF
C$_{IN}$	Digital input capacitance		−40°C to +125°C			2	pF
POWER SUPPLY							
I$_{DD}$	V$_{DD}$ supply current	Digital Inputs = 0 V or 5.5 V	25°C		0.007		µA
			−40°C to +125°C			2.6	µA

(1) When V$_S$ is 4.5 V, V$_D$ is 1.5 V or when V$_S$ is 1.5 V, V$_D$ is 4.5 V.

Electrical Characteristics (V_{DD} = 5 V ±10 %), GND = 0 V unless otherwise specified. (continued)

At T_A = 25°C, V_{DD} = 5 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
DYNAMIC CHARACTERISTICS							
t_{TRAN}	Switching time between channels	V_S = 3 V R_L = 200 Ω, C_L = 15 pF	25°C		12		ns
			−40°C to +85°C			19	ns
			−40°C to +125°C			20	ns
t_{OPEN} (BBM)	Break before make time	V_S = 3 V R_L = 200 Ω, C_L = 15 pF	25°C		40		ns
			−40°C to +85°C	1			ns
			−40°C to +125°C	1			ns
Q_C	Charge Injection	V_S = V_{DD} /2 R_S = 0 Ω, C_L = 1 nF	25°C		−10		pC
O_{ISO}	Off Isolation	R_L = 50 Ω, C_L = 5 pF f = 1 MHz	25°C		−65		dB
		R_L = 50 Ω, C_L = 5 pF f = 10 MHz	25°C		−45		dB
X_{TALK}	Crosstalk	R_L = 50 Ω, C_L = 5 pF f = 1 MHz	25°C		−65		dB
		R_L = 50 Ω, C_L = 5 pF f = 10 MHz	25°C		−45		dB
BW	Bandwidth	R_L = 50 Ω, C_L = 5 pF	25°C		400		MHz
C_{SOFF}	Source off capacitance	f = 1 MHz	25°C		8		pF
C_{SON} C_{DON}	On capacitance	f = 1 MHz	25°C		21		pF

Product Folder Links: *TMUX1237*

6.6 Electrical Characteristics (V_{DD} = 3.3 V ±10 %), GND = 0 V unless otherwise specified.

At T_A = 25°C, V_{DD} = 3.3 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
ANALOG SWITCH							
R_{ON}	On-resistance	V_S = 0 V to V_{DD} I_{SD} = 10 mA Refer to On-Resistance	25°C		4.5		Ω
			−40°C to +85°C			12.5	Ω
			−40°C to +125°C			13	Ω
ΔR_{ON}	On-resistance matching between channels	V_S = 0 V to V_{DD} I_{SD} = 10 mA Refer to On-Resistance	25°C		0.15		Ω
			−40°C to +85°C			1	Ω
			−40°C to +125°C			1	Ω
R_{ON} FLAT	On-resistance flatness	V_S = 0 V to V_{DD} I_{SD} = 10 mA Refer to On-Resistance	25°C		3.5		Ω
			−40°C to +85°C			4	Ω
			−40°C to +125°C			5	Ω
$I_{S(OFF)}$	Source off leakage current[1]	V_{DD} = 3.3 V Switch Off V_D = 3 V / 1 V V_S = 1 V / 3 V Refer to Off-Leakage Current	25°C		±75		nA
			−40°C to +85°C	−150		150	nA
			−40°C to +125°C	−175		175	nA
$I_{D(ON)}$ $I_{S(ON)}$	Channel on leakage current	V_{DD} = 3.3 V Switch On $V_D = V_S$ = 3 V / 1 V Refer to On-Leakage Current	25°C		±200		nA
			−40°C to +85°C	−500		500	nA
			−40°C to +125°C	−750		750	nA
LOGIC INPUTS							
V_{IH}	Input logic high		-40°C to 125°C	1.25		5.5	V
V_{IL}	Input logic low		-40°C to 125°C	0		0.8	V
I_{IH} I_{IL}	Input leakage current		25°C		±0.005		µA
I_{IH} I_{IL}	Input leakage current		−40°C to +125°C			±0.05	µA
C_{IN}	Logic input capacitance		25°C		1		pF
C_{IN}	Logic input capacitance		−40°C to +125°C			2	pF
POWER SUPPLY							
I_{DD}	V_{DD} supply current	Digital Inputs = 0 V or 5.5 V	25°C		0.004		µA
			−40°C to +125°C			1.6	µA

(1)   When V_S is 3 V, V_D is 1 V or when V_S is 1 V, V_D is 3 V.

Electrical Characteristics (V_{DD} = 3.3 V ±10 %), GND = 0 V unless otherwise specified. (continued)

At T_A = 25°C, V_{DD} = 3.3 V (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
DYNAMIC CHARACTERISTICS							
t_{TRAN}	Switching time between channels	V_S = 2 V R_L = 200 Ω, C_L = 15 pF	25°C		14		ns
			−40°C to +85°C			20	ns
			−40°C to +125°C			22	ns
t_{OPEN} (BBM)	Break before make time	V_S = 2 V R_L = 200 Ω, C_L = 15 pF	25°C		70		ns
			−40°C to +85°C	1			ns
			−40°C to +125°C	1			ns
Q_C	Charge Injection	V_S = V_{DD}/2 R_S = 0 Ω, C_L = 1 nF	25°C		−6		pC
O_{ISO}	Off Isolation	R_L = 50 Ω, C_L = 5 pF f = 1 MHz Refer to Off Isolation	25°C		−65		dB
		R_L = 50 Ω, C_L = 5 pF f = 10 MHz Refer to Off Isolation	25°C		−45		dB
X_{TALK}	Crosstalk	R_L = 50 Ω, C_L = 5 pF f = 1 MHz Refer to Crosstalk	25°C		−65		dB
		R_L = 50 Ω, C_L = 5 pF f = 10 MHz Refer to Crosstalk	25°C		−45		dB
BW	Bandwidth	R_L = 50 Ω, C_L = 5 pF Refer to Bandwidth	25°C		375		MHz
C_{SOFF}	Source off capacitance	f = 1 MHz	25°C		9		pF
C_{SON} C_{DON}	On capacitance	f = 1 MHz	25°C		23		pF

Product Folder Links: *TMUX1237*

6.7 Electrical Characteristics (V_{DD} = 1.8 V ±10 %), GND = 0 V unless otherwise specified.

At T_A = 25°C, V_{DD} = 1.8 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
ANALOG SWITCH							
R_{ON}	On-resistance	V_S = 0 V to V_{DD} I_{SD} = 10 mA Refer to On-Resistance	25°C		40		Ω
			−40°C to +85°C			80	Ω
			−40°C to +125°C			80	Ω
ΔR_{ON}	On-resistance matching between channels	V_S = 0 V to V_{DD} I_{SD} = 10 mA Refer to On-Resistance	25°C		0.4		Ω
			−40°C to +85°C			1.5	Ω
			−40°C to +125°C			1.5	Ω
$I_{S(OFF)}$	Source off leakage current [1]	V_{DD} = 1.98 V Switch Off V_D = 1.8 V / 1 V V_S = 1 V / 1.8 V Refer to Off-Leakage Current	25°C		±75		nA
			−40°C to +85°C	−150		150	nA
			−40°C to +125°C	−175		175	nA
$I_{D(ON)}$ $I_{S(ON)}$	Channel on leakage current	V_{DD} = 1.98 V Switch On V_D = V_S = 1.62 V / 1 V	25°C		±200		nA
			−40°C to +85°C	−500		500	nA
			−40°C to +125°C	−750		750	nA
DIGITAL INPUTS							
V_{IH}	Input logic high		−40°C to +125°C	1.07		5.5	V
V_{IL}	Input logic low		−40°C to +125°C	0		0.68	V
I_{IH} I_{IL}	Input leakage current		25°C		±0.005		µA
I_{IH} I_{IL}	Input leakage current		−40°C to +125°C			±0.05	µA
C_{IN}	Logic input capacitance		25°C		1		pF
C_{IN}	Logic input capacitance		−40°C to +125°C			2	pF
POWER SUPPLY							
I_{DD}	V_{DD} supply current	Logic Inputs = 0 V or 5.5 V	25°C		0.002		µA
			−40°C to +125°C			1	µA

(1)   When V_S is 1.8 V, V_D is 1 V or when V_S is 1 V, V_D is 1.8 V.

Electrical Characteristics (V_{DD} = 1.8 V ±10 %), GND = 0 V unless otherwise specified. (continued)

At T_A = 25°C, V_{DD} = 1.8 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
DYNAMIC CHARACTERISTICS							
t_{TRAN}	Switching time between channels	V_S = 1 V R_L = 200 Ω, C_L = 15 pF	25°C		24		ns
			−40°C to +85°C			44	ns
			−40°C to +125°C			45	ns
t_{OPEN} (BBM)	Break before make time	V_S = 1 V R_L = 200 Ω, C_L = 15 pF	25°C		85		ns
			−40°C to +85°C	1			ns
			−40°C to +125°C	1			ns
Q_C	Charge Injection	V_S = V_{DD}/2 R_S = 0 Ω, C_L = 1 nF	25°C		−3		pC
O_{ISO}	Off Isolation	R_L = 50 Ω, C_L = 5 pF f = 1 MHz Refer to Off Isolation	25°C		−65		dB
		R_L = 50 Ω, C_L = 5 pF f = 10 MHz Refer to Off Isolation	25°C		−45		dB
X_{TALK}	Crosstalk	R_L = 50 Ω, C_L = 5 pF f = 1 MHz Refer to Crosstalk	25°C		−65		dB
		R_L = 50 Ω, C_L = 5 pF f = 10 MHz Refer to Crosstalk	25°C		−45		dB
BW	Bandwidth	R_L = 50 Ω, C_L = 5 pF	25°C		250		MHz
C_{SOFF}	Source off capacitance	f = 1 MHz	25°C		9		pF
C_{SON} C_{DON}	On capacitance	f = 1 MHz	25°C		23		pF

Product Folder Links: *TMUX1237*

6.8 Electrical Characteristics (V_{DD} = 1.2 V ±10 %), GND = 0 V unless otherwise specified.

At T_A = 25°C, V_{DD} = 1.2 V (unless otherwise noted).

PARAMETER		TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
ANALOG SWITCH							
R_{ON}	On-resistance	V_S = 0 V to V_{DD} I_{DS} = 10 mA	25°C		70		Ω
			−40°C to +85°C			105	Ω
			−40°C to +125°C			105	Ω
ΔR_{ON}	On-resistance matching between channels	V_S = 0 V to V_{DD} I_{DS} = 10 mA	25°C		0.4		Ω
			−40°C to +85°C			1.5	Ω
			−40°C to +125°C			1.5	Ω
$I_{S(OFF)}$	Source off leakage current[1]	V_{DD} = 1.32 V Switch Off V_D = 1.2 V / 1 V V_S = 1 V / 1.2 V	25°C		±75		nA
			−40°C to +85°C	−150		150	nA
			−40°C to +125°C	−175		175	nA
$I_{D(ON)}$ $I_{S(ON)}$	Channel on leakage current	V_{DD} = 1.32 V Switch On $V_D = V_S$ = 1 V / 0.8 V	25°C		±200		nA
			−40°C to +85°C	−500		500	nA
			−40°C to +125°C	−750		750	nA
DIGITAL INPUTS							
V_{IH}	Input logic high		−40°C to +125°C	0.96			V
V_{IL}	Input logic low		−40°C to +125°C			0.36	V
I_{IH} I_{IL}	Input leakage current		25°C		±0.005		µA
I_{IH} I_{IL}	Input leakage current		−40°C to +125°C			±0.10	µA
C_{IN}	Digital input capacitance		25°C		1		pF
C_{IN}	Digital input capacitance		−40°C to +125°C			2	pF
POWER SUPPLY							
I_{DD}	V_{DD} supply current	Digital Inputs = 0 V or 5.5 V	25°C		0.002		µA
			−40°C to +125°C			0.9	µA
DYNAMIC CHARACTERISTICS							
t_{TRAN}	Switching time between channels	$V_{IN} = V_{DD}$ V_S = 1 V R_L = 200 Ω, C_L = 15 pF	25°C		40		ns
			−40°C to +85°C			300	ns
			−40°C to +125°C			300	ns
t_{OPEN} (BBM)	Break before make time	V_S = 1 V R_L = 200 Ω, C_L = 15 pF	25°C		425		ns
			−40°C to +85°C	1			ns
			−40°C to +125°C	1			ns
Q_C	Charge Injection	V_S = (V_{DD} + V_{SS})/2 R_S = 0 Ω, C_L = 1 nF	25°C		±5		pC
O_{ISO}	Off Isolation	R_L = 50 Ω, C_L = 5 pF f = 1 MHz	25°C		-64		dB
		R_L = 50 Ω, C_L = 5 pF f = 10 MHz	25°C		-44		dB
X_{TALK}	Crosstalk	R_L = 50 Ω, C_L = 5 pF f = 1 MHz	25°C		-64		dB
		R_L = 50 Ω, C_L = 5 pF f = 10 MHz	25°C		-44		dB
BW	Bandwidth	R_L = 50 Ω, C_L = 5 pF	25°C		250		MHz
C_{SOFF}	Source off capacitance	f = 1 MHz	25°C		9		pF
C_{SON} C_{DON}	On capacitance	f = 1 MHz	25°C		23		pF

(1)   When V_S is 1 V, V_D is 1.2 V or when V_S is 1.2 V, V_D is 1 V.

Product Folder Links: TMUX1237

6.9 Typical Characteristics

At T_A = 25°C, V_{DD} = 5 V (unless otherwise noted).
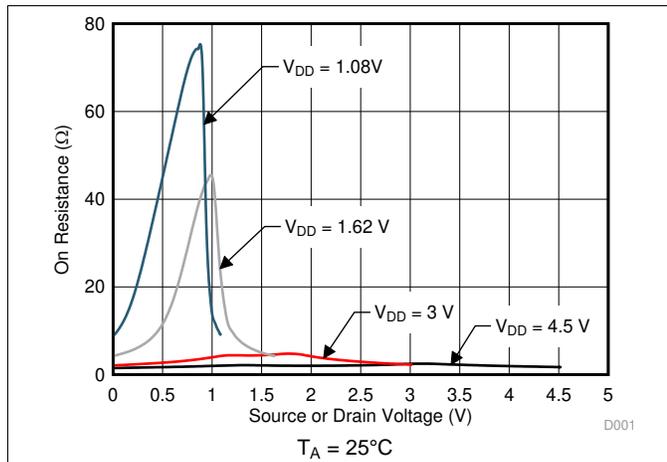
**Figure 1. On-Resistance vs Source or Drain Voltage**
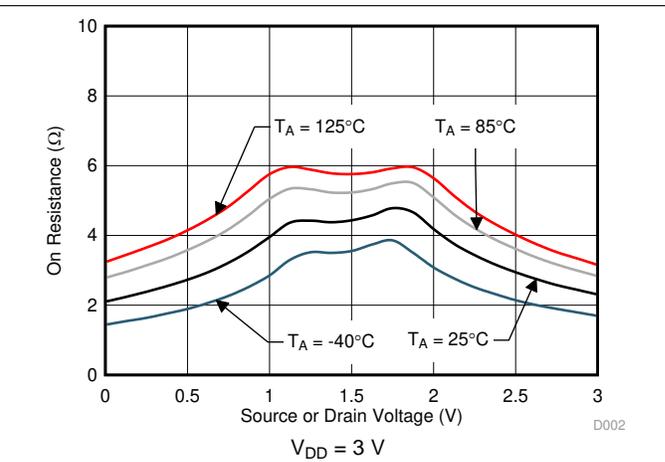

Figure 2. On-Resistance vs Source or Drain Voltage
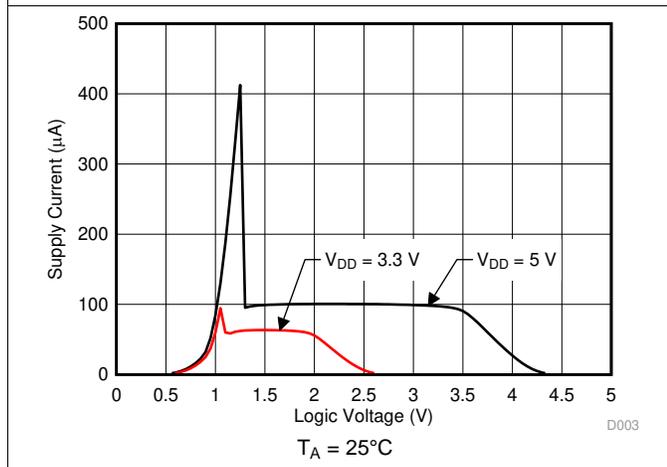


Figure 3. Supply Current vs Logic Voltage
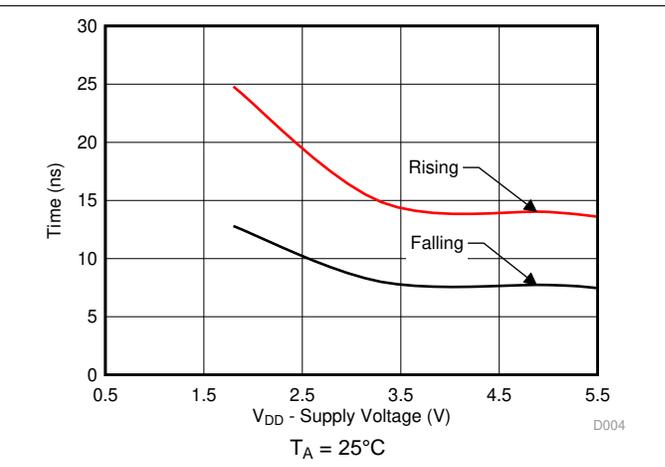
**Figure 4. T$_{transition}$ vs Supply Voltage**
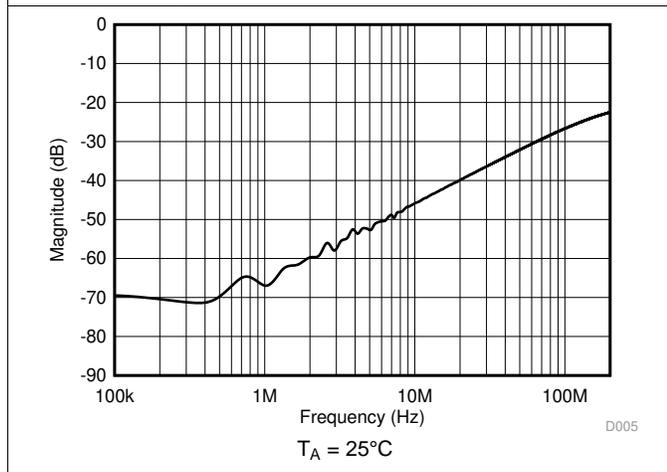
Figure 5. Crosstalk and Off-Isolation vs Frequency
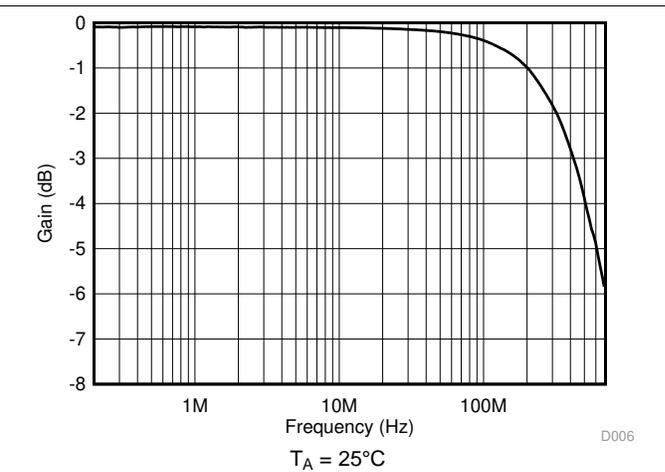

Figure 6. Frequency Response

7 Parameter Measurement Information

7.1 On-Resistance

The on-resistance of a device is the ohmic resistance between the source (Sx) and drain (D) pins of the device. The on-resistance varies with input voltage and supply voltage. The symbol R_{ON} is used to denote on-resistance. The measurement setup used to measure R_{ON} is shown in Figure 7. Voltage (V) and current (I_{SD}) are measured using this setup, and R_{ON} is computed with $R_{ON} = V / I_{SD}$:
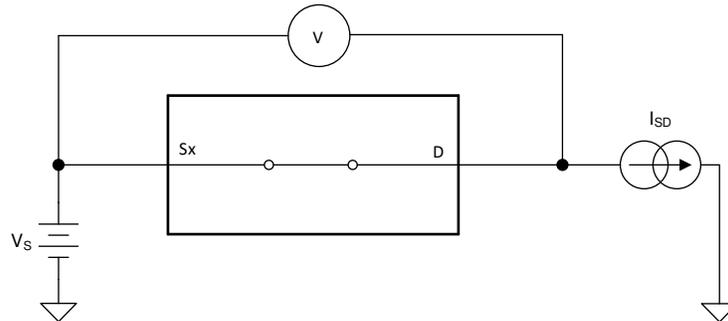
Figure 7. On-Resistance Measurement Setup

7.2 Off-Leakage Current

Source leakage current is defined as the leakage current flowing into or out of the source pin when the switch is off. This current is denoted by the symbol $I_{S(OFF)}$.

The setup used to measure off-leakage current is shown in Figure 8.
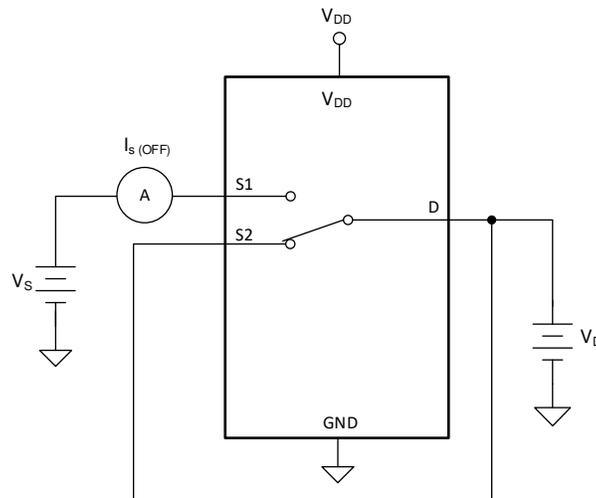
Figure 8. Off-Leakage Measurement Setup

Product Folder Links: *TMUX1237*

7.3 On-Leakage Current

Source on-leakage current is defined as the leakage current flowing into or out of the source pin when the switch is on. This current is denoted by the symbol $I_{S(ON)}$.

Drain on-leakage current is defined as the leakage current flowing into or out of the drain pin when the switch is on. This current is denoted by the symbol $I_{D(ON)}$.

Either the source pin or drain pin is left floating during the measurement. Figure 9 shows the circuit used for measuring the on-leakage current, denoted by $I_{S(ON)}$ or $I_{D(ON)}$.
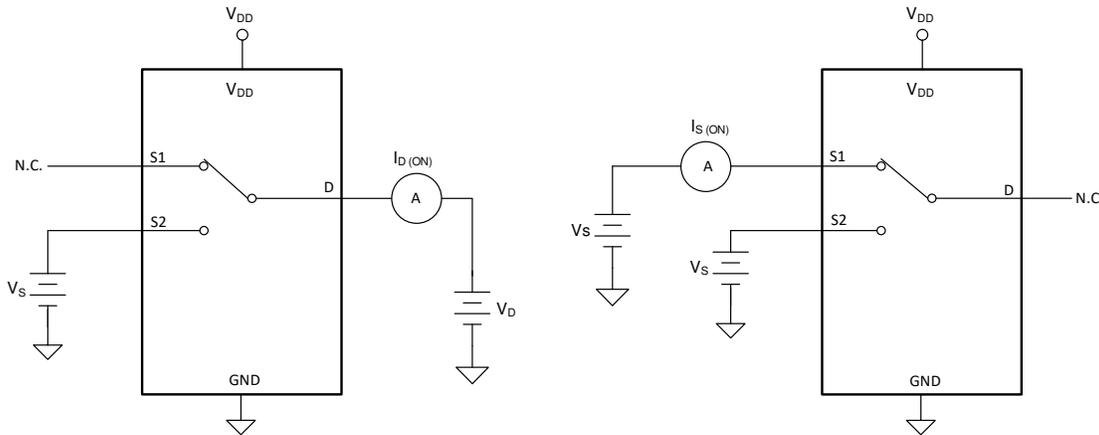
Figure 9. On-Leakage Measurement Setup

7.4 Transition Time

Transition time is defined as the time taken by the output of the device to rise or fall 10% after the logic control signal has risen or fallen past the logic threshold. The 10% transition measurement is utilized to provide the timing of the device. System level timing can then account for the time constant added from the load resistance and load capacitance. Figure 10 shows the setup used to measure transition time, denoted by the symbol $t_{TRANSITION}$.
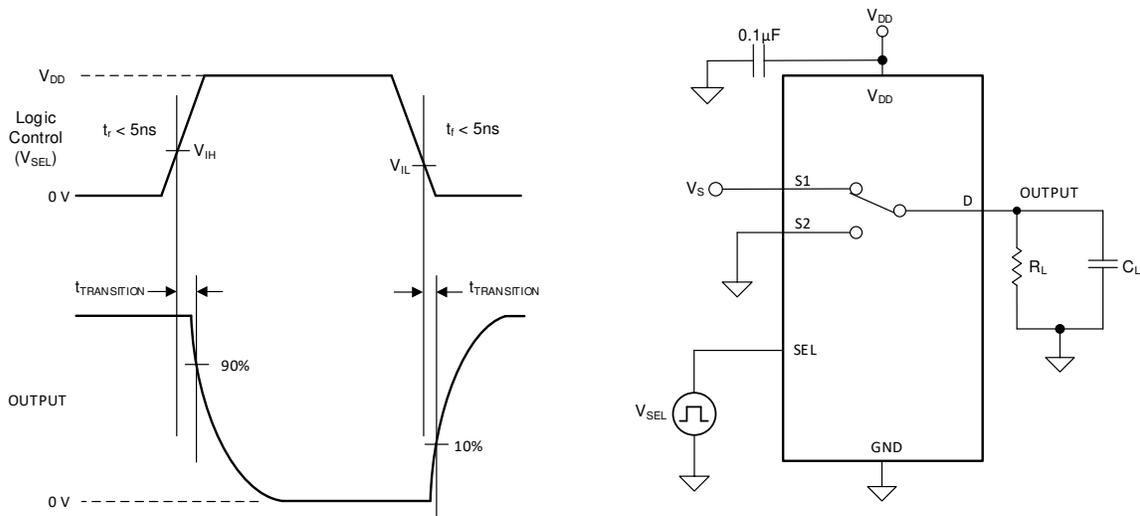
Figure 10. Transition-Time Measurement Setup

Product Folder Links: *TMUX1237*

7.5 Break-Before-Make

Break-before-make delay is a safety feature that prevents two inputs from connecting when the device is switching. The output first breaks from the on-state switch before making the connection with the next on-state switch. The time delay between the *break* and the *make* is known as break-before-make delay. Figure 11 shows the setup used to measure break-before-make delay, denoted by the symbol $t_{OPEN(BBM)}$.
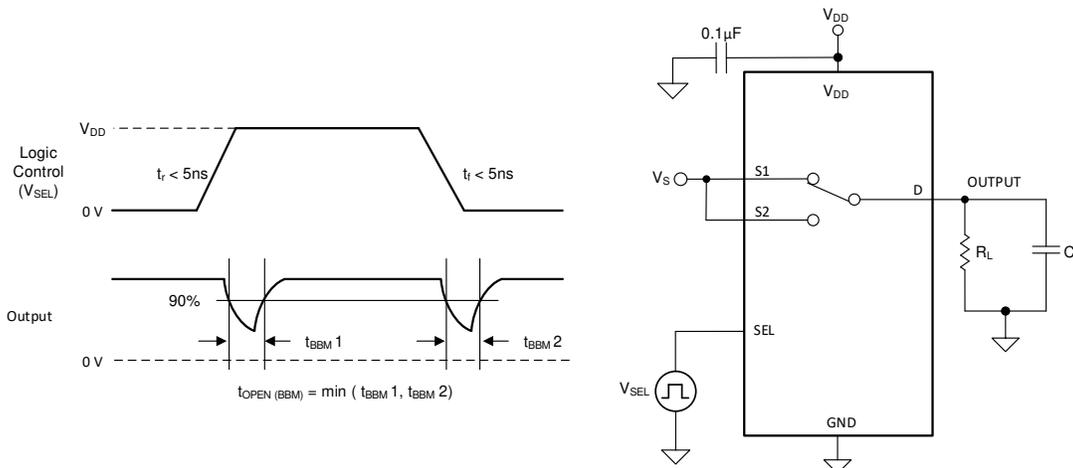

Figure 11. Break-Before-Make Delay Measurement Setup

7.6 Charge Injection

The TMUX1237 has a transmission-gate topology. Any mismatch in capacitance between the NMOS and PMOS transistors results in a charge injected into the drain or source during the falling or rising edge of the gate signal. The amount of charge injected into the source or drain of the device is known as charge injection, and is denoted by the symbol Q_C. Figure 12 shows the setup used to measure charge injection from Drain (D) to Source (Sx).
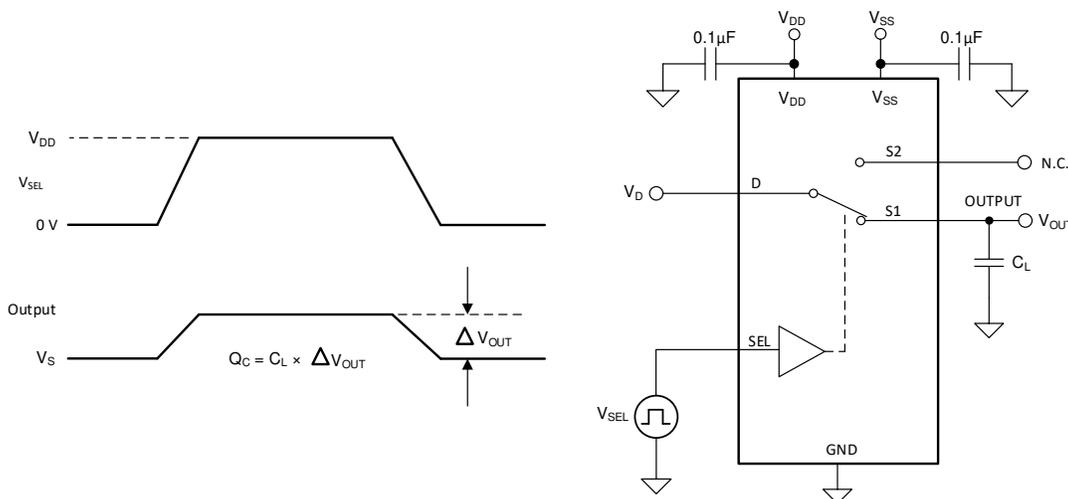

Figure 12. Charge-Injection Measurement Setup

Product Folder Links: *TMUX1237*

7.7 Off Isolation

Off isolation is defined as the ratio of the signal at the drain pin (D) of the device when a signal is applied to the source pin (Sx) of an off-channel. Figure 13 shows the setup used to measure, and the equation used to calculate off isolation.
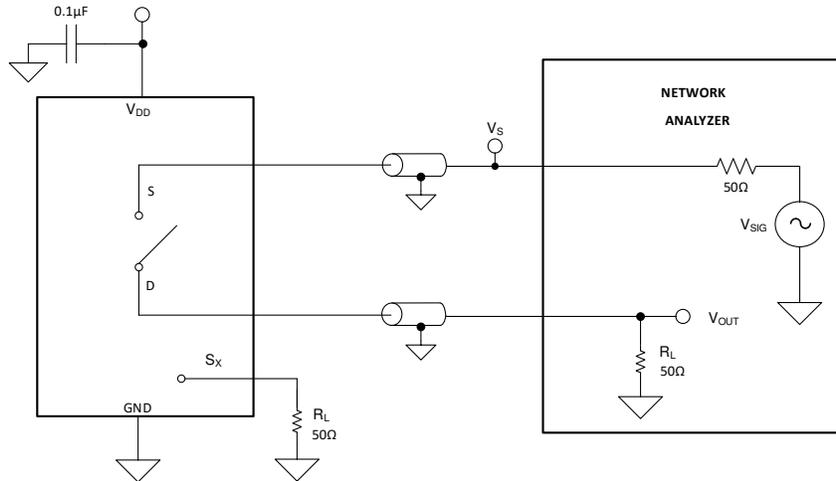

Figure 13. Off Isolation Measurement Setup

$$\text{Off Isolation} = 20 \cdot \text{Log}\left(\frac{V_{OUT}}{V_S}\right)$$

(1)

7.8 Crosstalk

Crosstalk is defined as the ratio of the signal at the drain pin (D) of a different channel, when a signal is applied at the source pin (Sx) of an on-channel. Figure 14 shows the setup used to measure, and the equation used to calculate crosstalk.
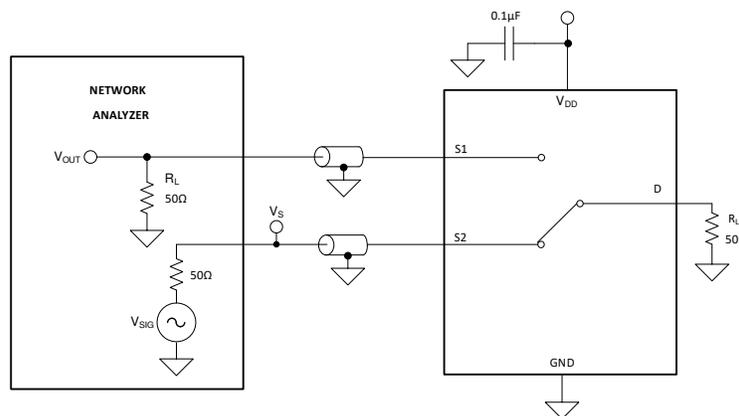

Figure 14. Crosstalk Measurement Setup

$$\text{Channel-to-Channel Crosstalk} = 20 \cdot \text{Log}\left(\frac{V_{OUT}}{V_S}\right)$$

(2)

Product Folder Links: *TMUX1237*

7.9 Bandwidth

Bandwidth is defined as the range of frequencies that are attenuated by less than 3 dB when the input is applied to the source pin (Sx) of an on-channel, and the output is measured at the drain pin (D) of the device. Figure 15 shows the setup used to measure bandwidth.
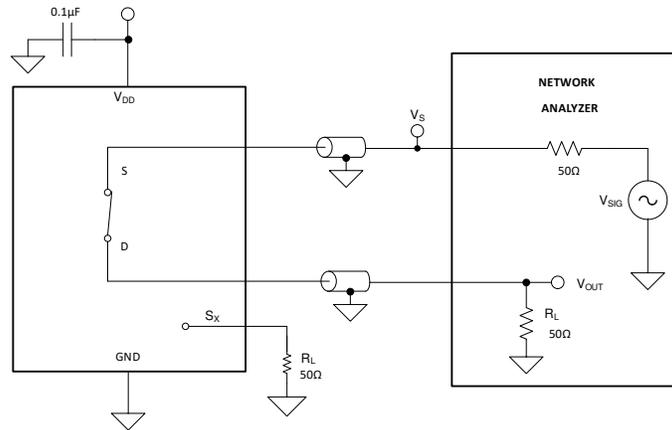

Figure 15. Bandwidth Measurement Setup

Product Folder Links: *TMUX1237*

8 Detailed Description

8.1 Overview

The TMUX1237 is an 2:1 (SPDT), 1-channel switch where the input is controlled with a single select (SEL) control pin.

8.2 Functional Block Diagram
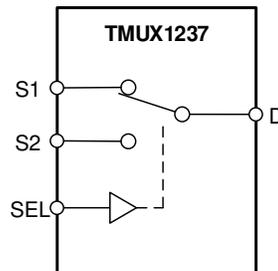
Figure 16. TMUX1237 Functional Block Diagram

8.3 Feature Description

8.3.1 Bidirectional Operation

The TMUX1237 conducts equally well from source (Sx) to drain (D) or from drain (D) to source (Sx). The device has very similar characteristics in both directions and supports both analog and digital signals.

8.3.2 Rail to Rail Operation

The valid signal path input/output voltage for TMUX1237 ranges from GND to V_{DD}.

8.3.3 1.8 V Logic Compatible Inputs

The TMUX1237 has 1.8-V logic compatible control for the logic control input (SEL). The logic input threshold scales with supply but still provides 1.8-V logic control when operating at 5.5 V supply voltage. 1.8-V logic level inputs allow the TMUX1237 to interface with processors that have lower logic I/O rails and eliminates the need for an external translator, which saves both space and BOM cost. For more information on 1.8 V logic implementations refer to *Simplifying Design with 1.8 V logic Muxes and Switches*

8.3.4 Fail-Safe Logic

The TMUX1237 supports Fail-Safe Logic on the control input pin (SEL) allowing for operation up to 5.5 V, regardless of the state of the supply pin. This feature allows voltages on the control pin to be applied before the supply pin, protecting the device from potential damage. Fail-Safe Logic minimizes system complexity by removing the need for power supply sequencing on the logic control pins. For example, the Fail-Safe Logic feature allows the select pin of the TMUX1237 to be ramped to 5.5 V while V_{DD} = 0 V. Additionally, the feature enables operation of the TMUX1237 with V_{DD} = 1.2 V while allowing the select pin to interface with a logic level of another device up to 5.5 V.

Product Folder Links: *TMUX1237*

8.4 Device Functional Modes

The select (SEL) pin of the TMUX1237 controls which switch is connected to the drain of the device. When a given input is not selected, that source pin is in high impedance mode (HI-Z). The control pins can be as high as 5.5 V.

The TMUX1237 can be operated without any external components except for the supply decoupling capacitors. Unused logic control pins should be tied to GND or V_{DD} in order to ensure the device does not consume additional current as highlighted in *Implications of Slow or Floating CMOS Inputs*. Unused signal path inputs (Sx or D) should be connected to GND.

8.5 Truth Tables

Table 1. TMUX1237 Truth Table

CONTROL LOGIC (SEL)	Selected Source (Sx) Connected To Drain (D) Pin
0	S1
1	S2

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9 Application and Implementation

> **NOTE**
>
> Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TMUX12xx family offers good system performance across a wide operating supply (1.08 V to 5.5 V). These devices include 1.8 V logic compatible control input pins that enable operation in systems with 1.8 V I/O rails. Additionally, the control input pin supports Fail-Safe Logic which allows for operation up to 5.5 V, regardless of the state of the supply pin. This protection stops the logic pins from back-powering the supply rail. These features of the TMUX12xx, a family of general purpose multiplexers and switches, reduce system complexity, board size, and overall system cost.

9.2 Typical Application

9.2.1 Input Control for Power Amplifier

One application of the TMUX1237 is for input control of a power amplifier. Utilizing a switch allows a system to control when the DAC is connected to the power amplifier, and can stop biasing the power amplifier by switching the gate to GND. Figure 17 shows the TMUX1237 configured for control of the power amplifier. The no overshoot when switching between inputs feature of the TMUX1237 is beneficial in applications such as this where the output is being switched across the full voltage range, and any overshoot on the output is undesired.
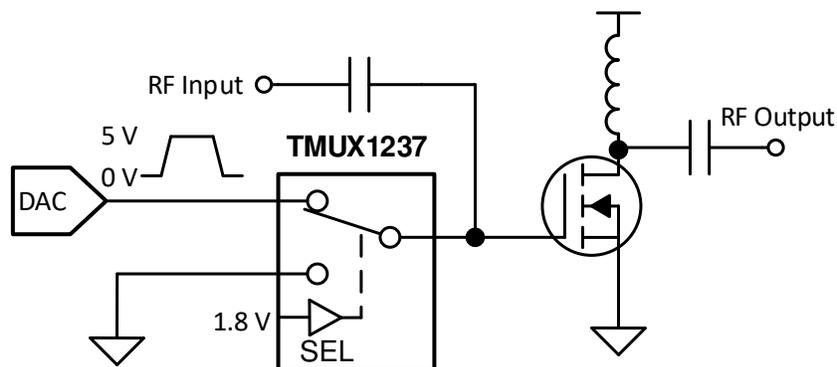

Figure 17. Input Control of Power Amplifier

9.2.1.1 Design Requirements

This design example uses the parameters listed in Table 3.

Table 2. Design Parameters

PARAMETERS	VALUES
Supply (V_{DD})	5 V
Switch I/O signal range	0 V to V_{DD} (Rail to Rail)
Control logic thresholds (SEL)	1.8 V compatible (up to 5.5 V)
Signal overshoot	0 V

9.2.1.2 Detailed Design Procedure

The application shown in Figure 17 demonstrates how to toggle between the DAC output and GND for control of a power amplifier using a single control input. The DAC output is utilized to bias the gate of the power amplifier and can be disconnected from the circuit using the select pin of the switch. The TMUX1237 helps eliminate overshoot in a system caused by switching between two different voltage levels on the source (Sx) input pins. Fast switching times create a step response on the output of switches or multiplexers which can cause system level overshoot and ringing depending on many factors such as load capacitance and board parasitics. The TMUX1237 improves system reliability by eliminating overshoot while still maintaining fast transition timing. The TMUX1237 can support 1.8-V logic signals on the control input, allowing the device to interface with low logic controls of an FPGA or MCU. The TMUX1237 can be operated without any external components except for the supply decoupling capacitors. The select pin is recommended to have a pull-down or pull-up resistor to ensure the input is in a known state if the control signal becomes disconnected. All inputs to the switch must fall within the recommend operating conditions of the TMUX1237 including signal range and continuous current. For this design with a supply of 5 V the signal range can be 0 V to 5 V and the max continuous current can be 50 mA.

9.2.1.3 Application Curve

The TMUX1237 improves system reliability by eliminating overshoot while still maintaining fast transition timing. Figure 18 shows no overshoot on the TMUX1237 Drain - Output when switching between GND and a 3.3 V input on the source pins. The logic voltage (SEL) toggles from GND to a 1.8 V logic input signal which cause the drain pin (D) to switch from GND to 3.3 V. No overshoot is observed on the output and the system level transition timing is 86 ns.
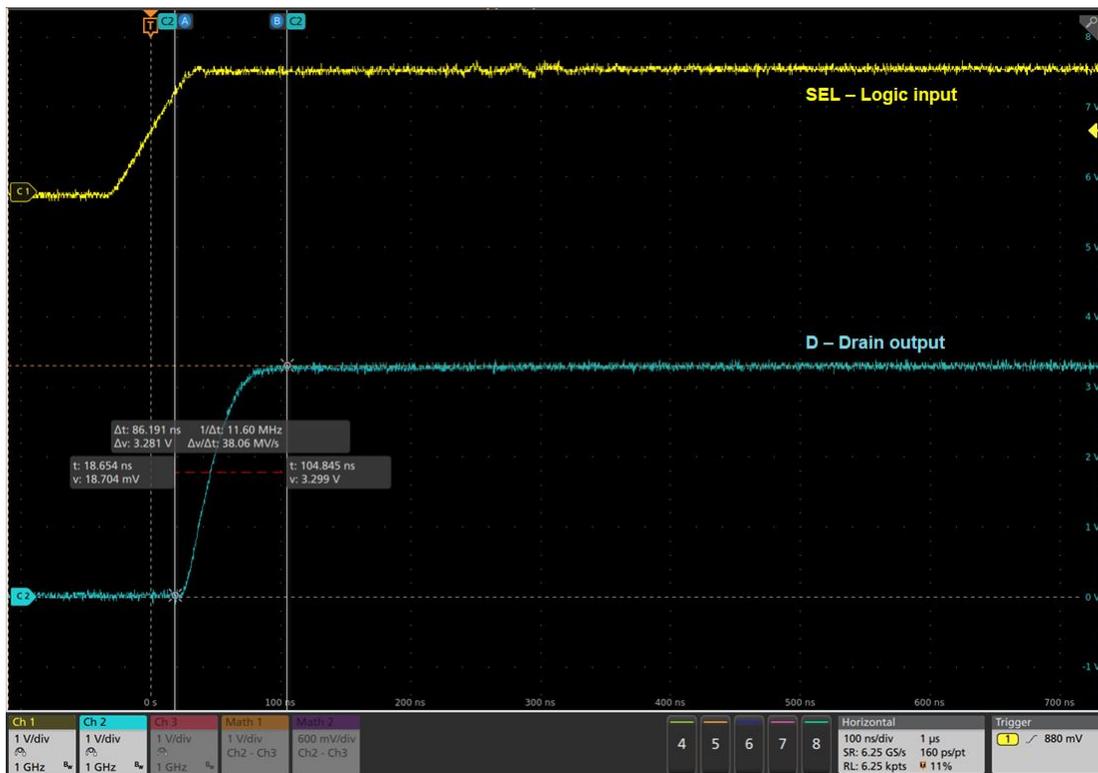
V_{DD} = 5 V
S_1 = 0 V
S_2 = 3.3 V
SEL = 0 V to 1.8 V

Figure 18. No Overshoot When Switching Between Inputs

9.2.2 Switchable Operational Amplifier Gain Setting

Another example application of the TMUX1237 is to change an Op Amp from unity gain setting to an inverting amplifier configuration. Utilizing a switch allows a system to have a configurable gain and allows the same architecture to be utilized across the board for various inputs to the system. shows the TMUX1237 configured for gain setting application.
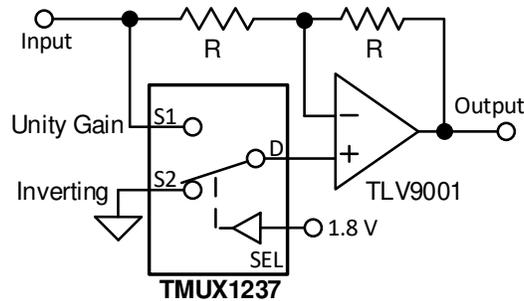

Figure 19. Switchable Op Amp Gain Setting

9.2.2.1 Design Requirements

This design example uses the parameters listed in Table 3.

Table 3. Design Parameters

PARAMETERS	VALUES
Input Signal	0 V to 2.75 V
Mux Supply (V_{DD})	2.75 V
Op Amp Supply (V_+/ V_-)	±2.75 V
Mux I/O signal range	0 V to V_{DD} (Rail to Rail)
Control logic thresholds	1.8 V compatible (up to 5.5 V)

9.2.2.2 Detailed Design Procedure

The application shown in demonstrates how to use a single control input and toggle between gain settings of -1 and +1. If switching between inverting and unity gain is not required, the TMUX1237 can be utilized in the feedback path to select different feedback resistors and provide scalable gain settings for configurable signal conditioning.

The TMUX1237 can be operated without any external components except for the supply decoupling capacitors. The select pin is recommended to have a pull-down or pull-up resistor to ensure the input is in a known state if the control signal becomes disconnected. All inputs to the switch must fall within the recommend operating conditions of the TMUX1237 including signal range and continuous current. For this design with a supply of 2.75 V the signal range can be 0 V to 2.75 V and the max continuous current can be 50 mA.

9.2.2.3 Application Curve
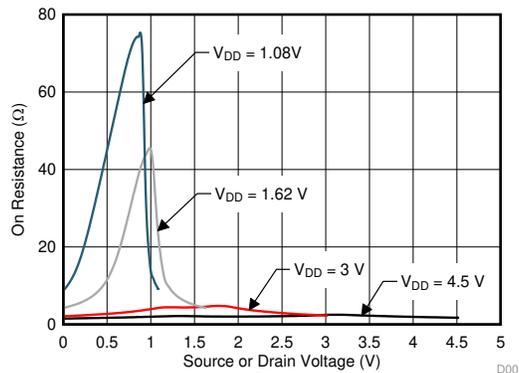
$T_A = 25°C$

Figure 20. On-Resistance vs Source or Drain Voltage

10 Power Supply Recommendations

The TMUX1237 operates across a wide supply range of 1.08 V to 5.5 V. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices.

Power-supply bypassing improves noise margin and prevents switching noise propagation from the V_{DD} supply to other components. Good power-supply decoupling is important to achieve optimum performance. For improved supply noise immunity, use a supply decoupling capacitor ranging from 0.1 μF to 10 μF from V_{DD} to ground. Place the bypass capacitors as close to the power supply pins of the device as possible using low-impedance connections. TI recommends using multi-layer ceramic chip capacitors (MLCCs) that offer low equivalent series resistance (ESR) and inductance (ESL) characteristics for power-supply decoupling purposes. For very sensitive systems, or for systems in harsh noise environments, avoiding the use of vias for connecting the capacitors to the device pins may offer superior noise immunity. The use of multiple vias in parallel lowers the overall inductance and is beneficial for connections to ground planes.

11 Layout

11.1 Layout Guidelines

11.1.1 Layout Information

When a PCB trace turns a corner at a 90° angle, a reflection can occur. A reflection primarily occurs because the width of the trace changes. At the apex of the turn, the trace width increases to 1.414 times its width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self–inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. Figure 21 shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.
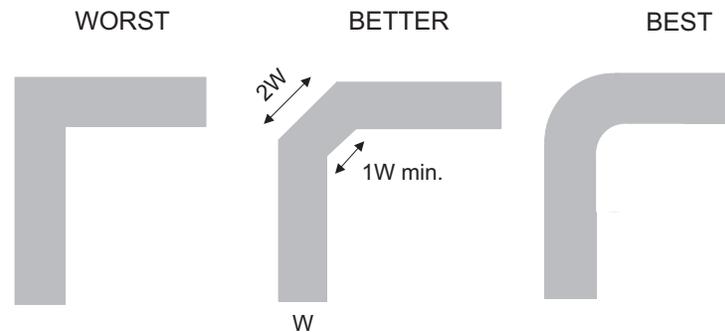

Figure 21. Trace Example

Route high-speed signals using a minimum of vias and corners which reduces signal reflections and impedance changes. When a via must be used, increase the clearance size around it to minimize its capacitance. Each via introduces discontinuities in the signal's transmission line and increases the chance of picking up interference from the other layers of the board. Be careful when designing test points, through-hole pins are not recommended at high frequencies.

Figure 22 illustrates an example of a PCB layout with the TMUX1237. Some key considerations are:

* Decouple the V_{DD} pin with a 0.1-µF capacitor, placed as close to the pin as possible. Make sure that the capacitor voltage rating is sufficient for the V_{DD} supply.
* Keep the input lines as short as possible.
* Use a solid ground plane to help reduce electromagnetic interference (EMI) noise pickup.
* Do not run sensitive analog traces in parallel with digital traces. Avoid crossing digital and analog traces if possible, and only make perpendicular crossings when necessary.

11.2 Layout Example
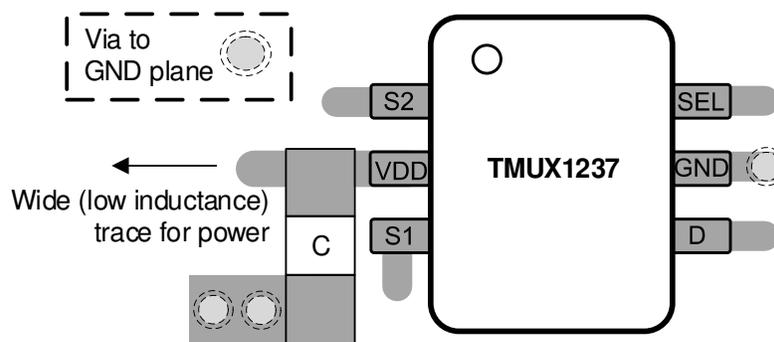
Figure 22. TMUX1237 Layout Example

Product Folder Links: *TMUX1237*

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

Texas Instruments, *Improve Stability Issues with Low CON Multiplexers*.

Texas Instruments, *Simplifying Design with 1.8 V logic Muxes and Switches*.

Texas Instruments, *Eliminate Power Sequencing with Powered-off Protection Signal Switches*.

Texas Instruments, *System-Level Protection for High-Voltage Analog Multiplexers*.

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Community Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.4 Trademarks

E2E is a trademark of Texas Instruments.

12.5 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

SLYZ022 — *TI Glossary*.
   This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TMUX1237DCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	237	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers
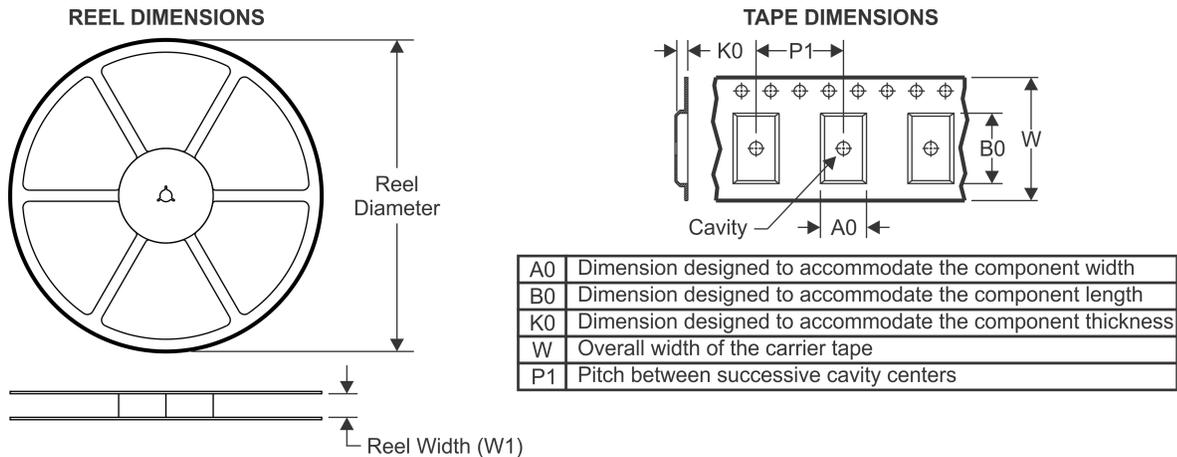
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
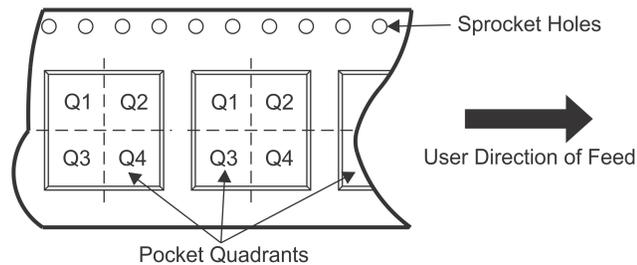
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TMUX1237DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

![Texas Instruments logo]

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS
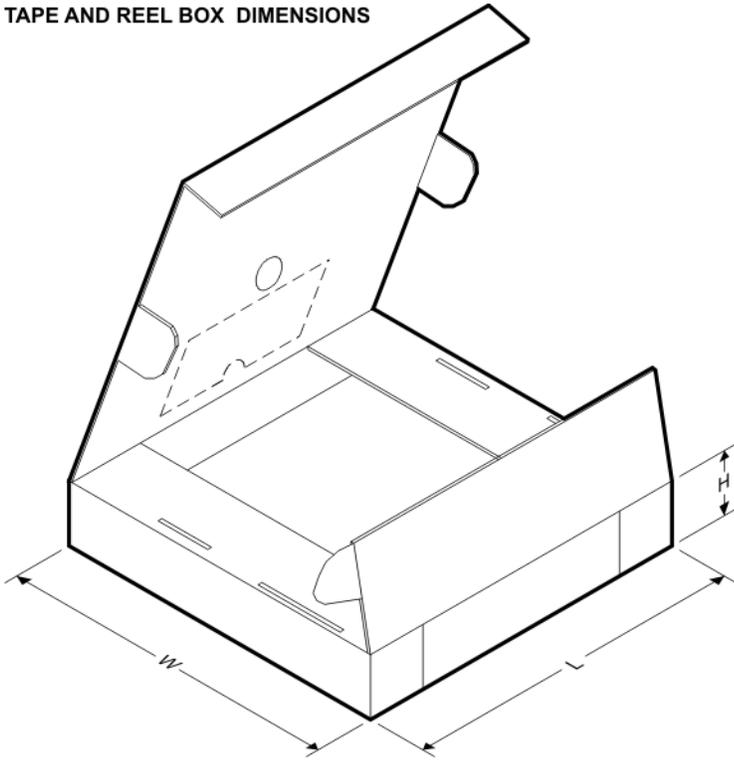
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TMUX1237DCKR	SC70	DCK	6	3000	180.0	180.0	18.0

DCK (R−PDSO−G6)   PLASTIC SMALL−OUTLINE PACKAGE
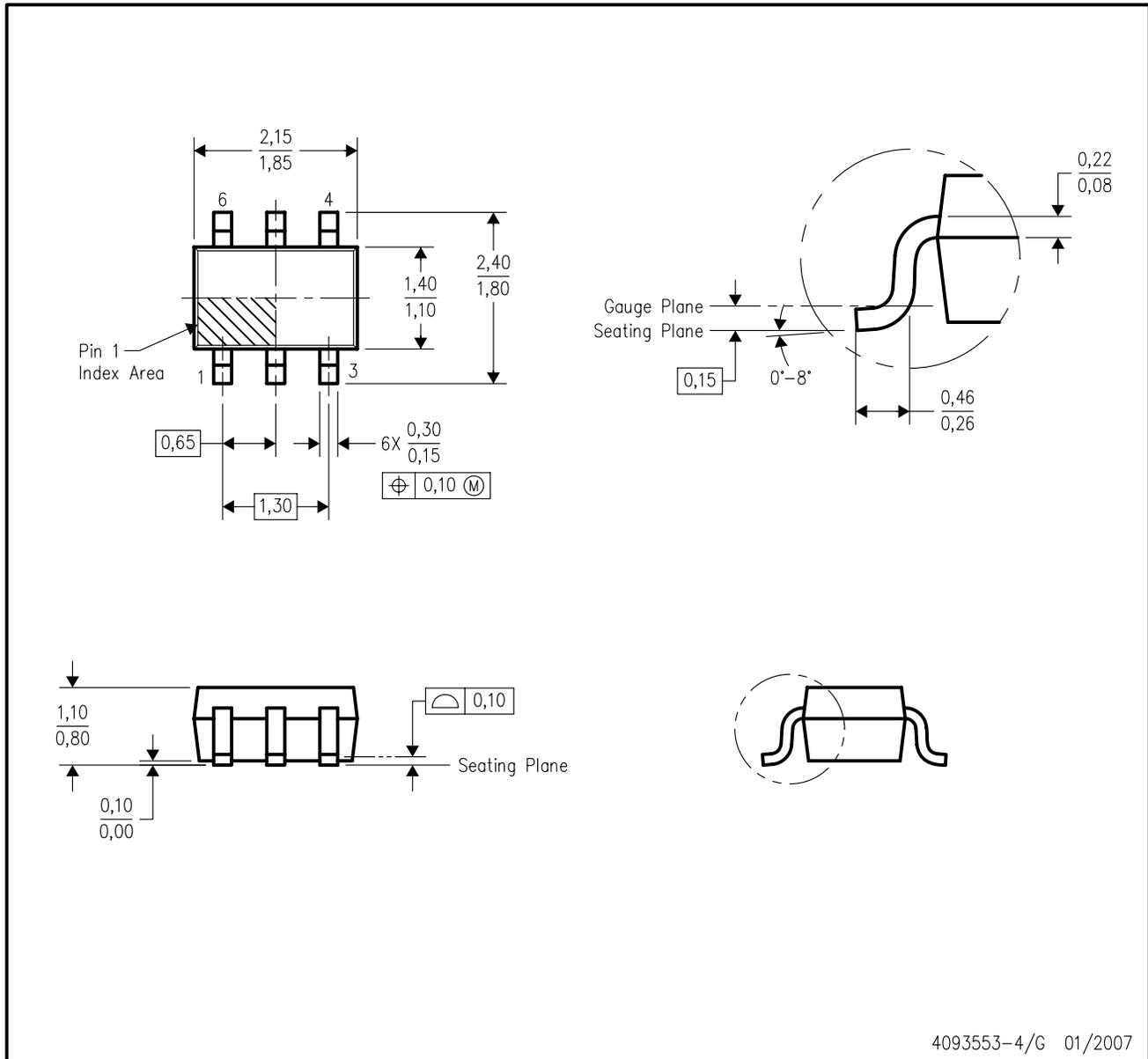
4093553−4/G   01/2007

NOTES: A.   All linear dimensions are in millimeters.
         B.   This drawing is subject to change without notice.
         C.   Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
         D.   Falls within JEDEC MO−203 variation AB.

DCK (R−PDSO−G6)   PLASTIC SMALL OUTLINE
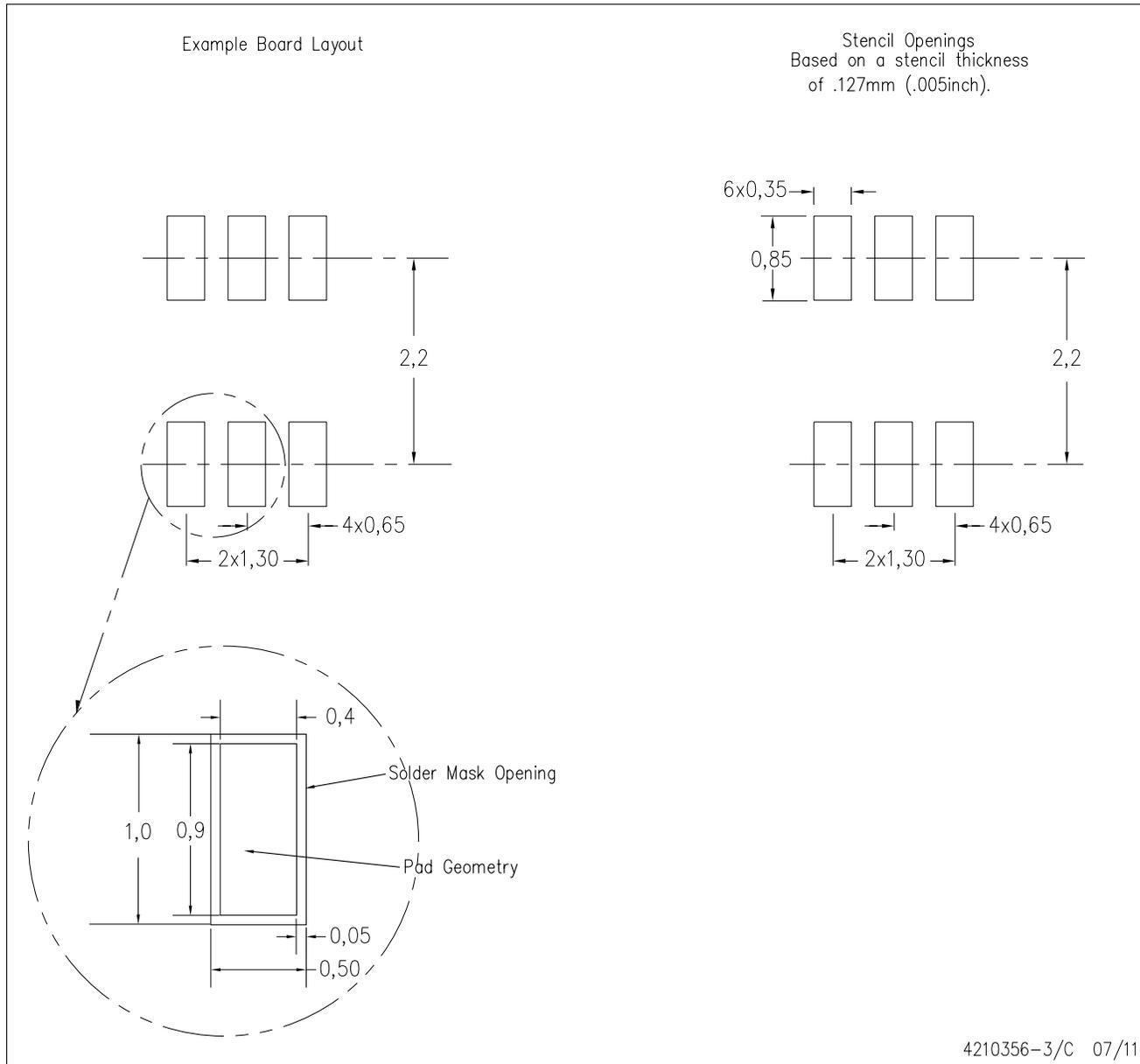
Example Board Layout

Stencil Openings
Based on a stencil thickness
of .127mm (.005inch).

6x0,35

0,85

2,2

2,2

4x0,65

2x1,30

4x0,65

2x1,30

0,4

Solder Mask Opening

1,0   0,9

Pad Geometry

0,05

0,50

4210356−3/C 07/11

NOTES: A. All linear dimensions are in millimeters.
         B. This drawing is subject to change without notice.
         C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
         D. Publication IPC−7351 is recommended for alternate designs.
         E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
             contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric
             metal load solder paste. Refer to IPC−7525 for other stencil recommendations.